# FAIRCHILD

SEMICONDUCTOR®

# FAN2560 350mA Low-V<sub>IN</sub> LDO with Fast Transient Response

#### Features

- 55µA Typical Quiescent Current
- Up to 350mA Output Current
- 2.9V to 5.5V Bias Supply Voltage
- V<sub>OUT</sub>+0.1V to 5.5V Power Input Supply Voltage
- Fixed Voltage Options: 1.3V and 1.5V
- Thermal Shutdown Protection (TSD)
- Input Under-Voltage Lockout (UVLO)
- Short-Circuit Current Protection (SCP)
- 5-bump 0.96 x 1.33mm WLCSP

#### **Applications**

- Moderate Current Digital Loads
- DVB-H, DMB Processors
- Handsets, Smartphones
- WLAN DC-DC Converter Modules
- PDA, DSC, PMP, and MP3 Players
- Portable Hard Disk Drives

## **Typical Applications**

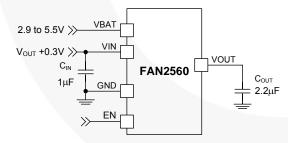


Figure 1. Separate Supply and Bias Line

# The FAN2560 is a linear low-dropout (LDO) regulator with a split-supply architecture. Separate bias and

Description

with a split-supply architecture. Separate bias and supply inputs allow bias to be taken directly from the battery, while the input is taken from a lower pre-regulated source. This allows a smaller differential voltage between input and output, which provides greater efficiency over a wider  $V_{BAT}$  range.

The FAN2560 is available in a fixed-voltage output, 5-bump, WLCSP package.

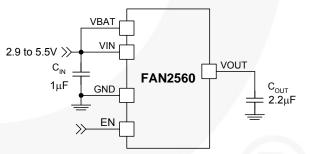
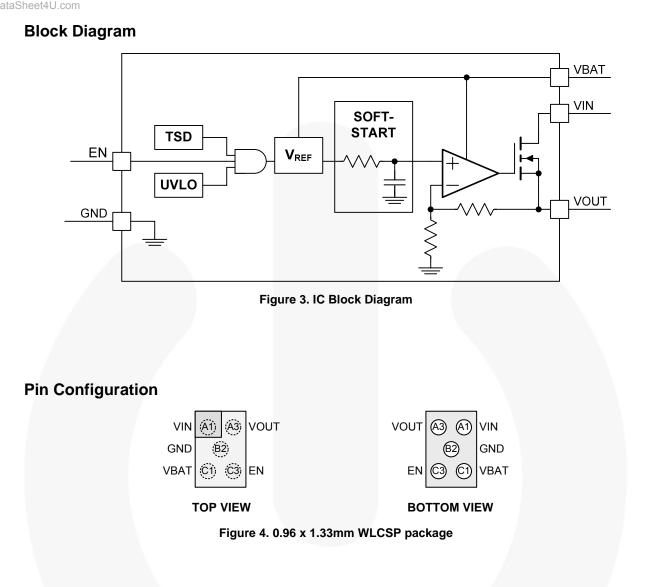


Figure 2. Connected Supply and Bias Line

#### **Ordering Information**

Part Number	Operating Temperature Range	Package	Packing Method
FAN2560UC13X	-40°C to 85°C	WLCSP-5 0.96 x 1.33mm	Tape and Reel
FAN2560UC15X	-40°C to 85°C	WLCSP-5 0.96 x 1.33mm	Tape and Reel
			1

All packages are lead free per JEDEC: J-STD-020B standard.



## **Pin Definitions**

Pin #	Name	Description
A1	VIN	Power supply input. A minimum 1µF MLCC is required to GND.
A3	VOUT	Output Voltage. A typical $C_{\text{OUT}}$ =1 $\mu F$ to 2.2 $\mu F$ MLCC is required to GND, placed close to the $V_{\text{OUT}}$ terminal.
C1	VBAT	Battery bias supply input. No capacitor is required unless another bulk capacitor is more than few inches away.
C3	EN	Enable input. The device is in shutdown mode when the voltage at this pin is <0.4V and enabled when >1.1V. The EN latches the LOW logic state once externally forced. Do not leave this pin floating when the device is turned ON.
B2	GND	Ground pin. Connect to a PCB GND plane.

#### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Parameter	Min.	Max.	Units
	V <sub>BAT</sub> , V <sub>IN</sub> , EN		-0.3	6.0	V
V <sub>OUT</sub>	Output Voltage		-0.3	V <sub>IN</sub> + 0.3V	V
TJ	Junction Temperature		-40	+150	°C
T <sub>STG</sub>	Storage Temperature		-65	+150	°C
TL	Lead Soldering Temperat	ure, 10 Seconds		+260	°C
ESD	Electrostatic Discharge	Human Body Model per JESD22-A114	3.5		kV
ESD	Protection Level	Charged Device Model per JESD22-C101	1.5		κv

#### **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Тур.	Max.	Units
V <sub>BAT</sub>	Bias Supply Range, (V <sub>OUT</sub> + 1.4V) < V <sub>BAT</sub>	2.9		5.5	V
V <sub>IN</sub>	Power Supply Range, $(V_{IN} < V_{BAT})$	$V_{OUT} + V_{DO}$		V <sub>BAT</sub>	V
IOUT	Output Current	0		350	mA
CIN	Input Capacitor (Effective Capacitance)	0.7	1.0		μF
CIN	Equivalent Series Resistance (ESR)	0		300	mΩ
Cout	Output Capacitor (Effective Capacitance)	0.7	2.2	12.0	μF
COUT	Equivalent Series Resistance (ESR)	3		300	mΩ
T <sub>A</sub>	Operating Ambient Temperature Range	-40		+85	°C
TJ	Operating Junction Temperature Range	-40		+125	°C

#### **Thermal Properties**

Symbol	Parameter	Min.	Тур.	Max.	Units
Θ <sub>JA</sub>	Junction-to-Ambient Thermal Resistance		180 <sup>(1)</sup>		°C/W

Note:

1 Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with four-layer boards in accordance to JESD51- JEDEC standard. Special attention must be paid not to exceed junction temperature T<sub>J(max)</sub> at a given ambient temperature T<sub>A</sub>.

## **Electrical Characteristics**

 $V_{BAT}$ =2.9V to 5.5V,  $V_{IN}$ = $V_{OUT}$  + 0.3V,  $T_A$ =-40°C to +85°C, Test Circuit Figure 1, unless otherwise noted. Typical values are at  $T_A$ =25°C,  $V_{BAT}$ =3.6V,  $I_{LOAD}$ =1mA,  $V_{EN}$ =1.8V.

Symbol	Parameter	Conditions		Min.	Тур.	Max.	Units
Power Sup	plies						
V <sub>BAT</sub>	Battery Input Supply	(V <sub>OUT</sub> + 1.4V) <	V <sub>BAT</sub>	2.9		5.5	V
V <sub>IN</sub>	Input Voltage Range	V <sub>IN</sub> < V <sub>BAT</sub>		V <sub>OUT</sub> + V <sub>DO</sub>		VBAT	V
I <sub>BAT</sub>	V <sub>BAT</sub> Supply Current	I <sub>LOAD</sub> =0µA			55	70	μA
l <sub>iN</sub>	V <sub>IN</sub> Supply Current	I <sub>LOAD</sub> =0µA			4	11	μA
IVBATSD	V <sub>BAT</sub> Shutdown Supply Current	V <sub>BAT</sub> =3.6V, EN=	=GND		0.01	1.00	μA
I <sub>VINSD</sub>	V <sub>IN</sub> shutdown Supply Current	V <sub>BAT</sub> =3.6V, EN=	=GND		0.01	1.00	μA
V <sub>UVLO</sub>	Under-voltage Lockout Threshold	V <sub>BAT</sub> Falling Ed Hysteresis	ge		2.0 0.05	2.4	V V
	Enable High-level Input Voltage			1.1			
$V_{(EN)}$	Enable Low-level Input Voltage					0.4	V
I <sub>(EN)</sub>	Enable Input Leakage Current	EN=VIN or GND	)		0	0.5	μA
Regulation						l	· ·
I <sub>OUT</sub>	Maximum Output Current			350			mA
V <sub>DO</sub>	Dropout Voltage with Respect to $V_{IN}^{(2)}$	I <sub>LOAD</sub> =350mA			70	200	mV
$\Delta V_{OUT}$	Output Voltage Accuracy	Over Full V <sub>IN</sub> , I <sub>C</sub> Temperature R		-2		2	%
$\Delta V_{\text{OUTline}}$	Line Regulation	Over Full VIN, VBAT, IOUT			- 6		m)/
$\Delta V_{\text{OUTIoad}}$	Load Regulation	Range			< 6		mV
I <sub>SCP</sub>	Short-circuit Current Limit				400		mA
		V <sub>BAT</sub> and V <sub>IN</sub> applied, EN	3V <v<sub>BAT &lt;4.5V</v<sub>		130	300	
I <sub>SU</sub>	Start-up Peak Current	from L to H, no load, T <sub>A</sub> = -30C to +85C	2.9V <v<sub>BAT &lt;5.5V</v<sub>			500	mA
TOD		Rising Tempera	ature		150		°C
TSD	Thermal Shutdown	Hysteresis			10		°C
DODD	Devues Oversky Deie stien Detie	$V_{IN}$ , 10Hz to 10	kHz		> 60		
PSRR	Power Supply Rejection Ratio	$V_{BAT}$ , 10Hz to 1	0kHz		> 50		dB
en	Output Noise Voltage	10Hz to 100kHz			60		μV <sub>RMS</sub>
Timing Cha	aracteristics	•					
$\begin{array}{c} \text{Peak} \\ \Delta V_{\text{OUTline}} \end{array}$	Line Transient Response	600mV, t <sub>RISE</sub> =t <sub>F</sub>	<sub>ALL</sub> =10µs		±2		mV
$\begin{array}{c} \text{Peak} \\ \Delta V_{\text{OUTload}} \end{array}$	Load Transient Response	0 to 300mA, t <sub>RIS</sub>	<sub>SE</sub> =t <sub>FALL</sub> =1µs		±15		mV
t <sub>on</sub>	Turn-on Time				70	200	μs

2 Dropout voltage is the minimum input to output differential voltage needed to maintain  $V_{\text{OUT}}$  in regulation, in specified conditions

#### **Typical Characteristics**

 $Unless otherwise specified, C_{IN}=1 \mu F ceramic, C_{OUT}=2.2 \mu F ceramic, V_{IN}=V_{OUTnom} + 0.3 V, V_{BAT}=3.6 V, T_{A}=25 C, V_{EN}=1.8 V.$ 

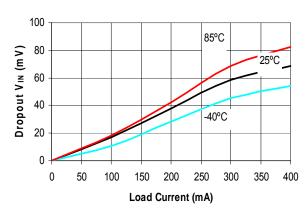


Figure 5. Dropout Voltage vs. Load Current

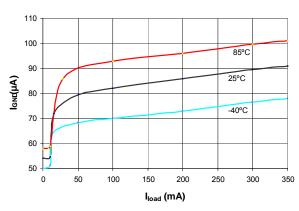


Figure 7. GND Current vs. Load Current

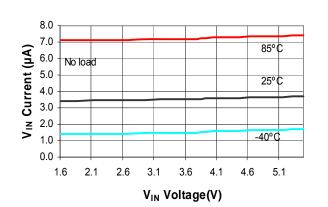


Figure 9. Input V<sub>IN</sub> Quiescent Current (V<sub>BAT</sub>=5.5V)

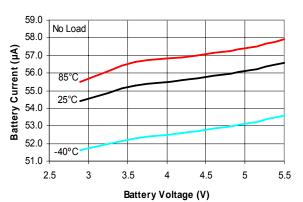
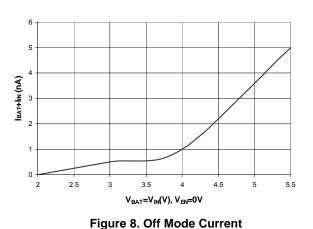
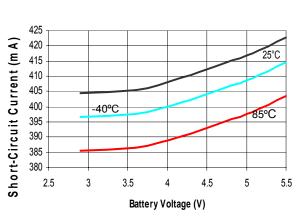
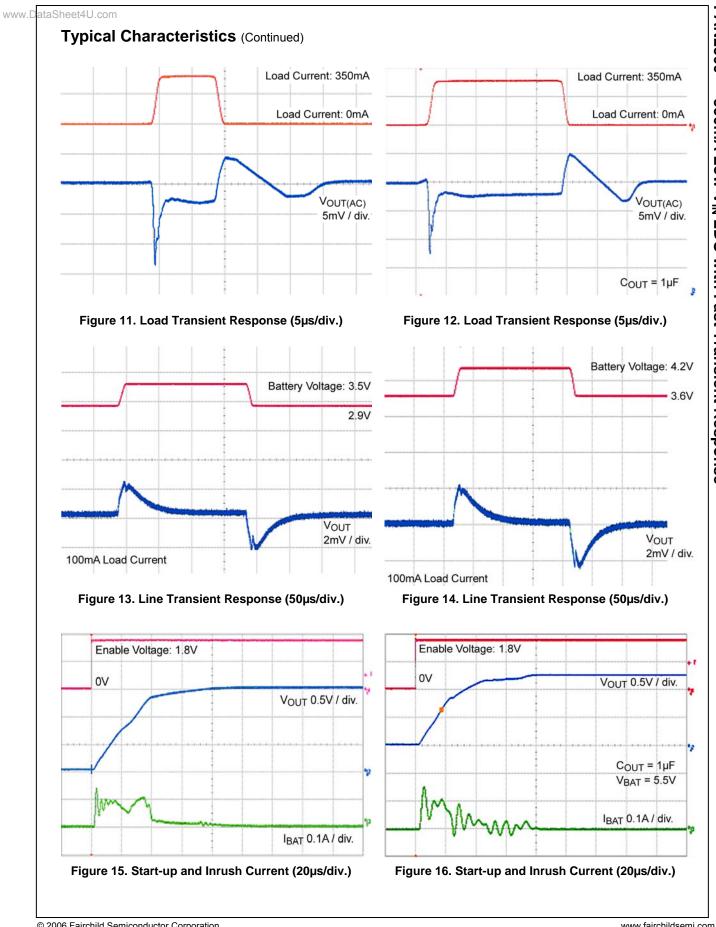


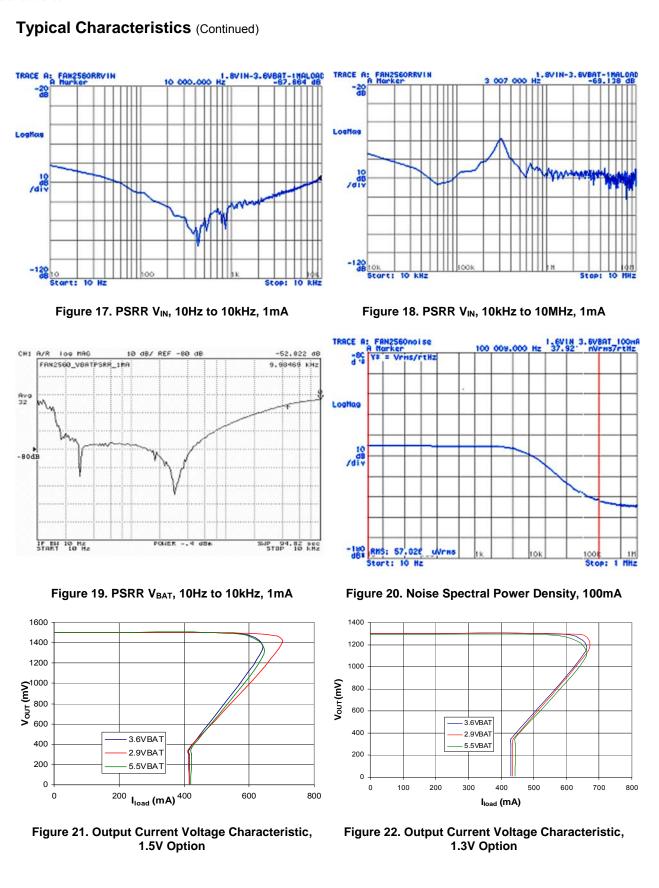
Figure 6. Battery Quiescent Supply Current











#### **Application Information**

#### **ENABLE Latch**

A pull-down resistor latches the LOW state of the EN input after this input is externally forced LOW. A lowside switch turns ON a 370 k $\Omega$  pull-down resistance to keep the EN in LOW state, even if the EN input is subsequently left floating.

#### Soft-Start

A soft-start function prevents an excessive input current flow during start-up. When the LDO is enabled, the soft-start circuit limits the peak inrush current below the specified maximum value, which increases when  $C_{OUT}$  increases. To further reduce the peak inrush current, the output capacitance may be lowered to 1µF, taking advantage of FAN2560 stability over a wide range of  $C_{OUT}$  capacitance.

#### **Short-Circuit and Thermal Protection**

The FAN2560 output current voltage characteristic has a fold-back shape that indicates a short-circuit current limit lower than the maximum load current. Although the short-circuit current is limited to below 500mA, the device can supply high peak output currents of up to 1A for brief periods. However, this output overload may cause the die temperature to increase and exceed maximum ratings due to power dissipation. In such cases, depending upon the ambient temperature, VIN, load current, and the junction-to-air thermal resistance  $(\theta_{JA})$  of the die, the device may enter thermal shutdown. During output overload conditions, when the die temperature exceeds the shutdown limit temperature of 150°C, the onboard thermal protection disables the output until the temperature drops below this limit, at which point the output is re-enabled.

#### **Thermal Considerations**

For best performance, the die temperature and the power dissipated should be kept at moderate values. The maximum power dissipated can be evaluated based on the following relationship:

$$\mathsf{P}_{\mathsf{D}(\mathsf{max})} = \left\{ \frac{\mathsf{T}_{\mathsf{J}(\mathsf{max})} - \mathsf{T}_{\mathsf{A}}}{\Theta_{\mathsf{IA}}} \right\}$$
(1)

where  $T_{J(max)}$  is the maximum allowable junction temperature of the die, which is 125°C, and  $T_A$  is the ambient operating temperature.  $\theta_{JA}$  is dependent on the surrounding PCB layout and can be improved by providing a heat sink of surrounding copper ground.

The addition of backside copper with through-holes, stiffeners, and other enhancements can also aid in reducing  $\theta_{JA}$ . The heat contributed by the dissipation of other devices located nearby must be included in design considerations.

#### **Reverse Current Path**

During normal operation,  $V_{IN}$  is higher than  $V_{OUT}$  and the parasitic diode for the series power FET is reverse biased. If the output voltage is externally forced above the input voltage, the parasitic diode gets forward biased and starts to conduct. In this case, it is necessary to limit the reverse current to maximum 100mA to avoid adversely affecting reliability.

#### **Capacitors Selection**

The FAN2560 is stable with a wide range of ceramic output capacitors. An output capacitor of at least  $0.7\mu$ F effective capacitance and the minimum ESR over the frequency range of 3 to  $300m\Omega$  is required to ensure stability over the full range of supply voltages and load currents. High-ESR tantalum or electrolytic capacitors may be used, but a low ESR ceramic capacitor has to be connected in parallel at the output, at a distance no more than 1-inch from the VOUT pin. The MLCC capacitors indicated in Table 1 have been successfully tested with the FAN2560.

Capaci	itors	

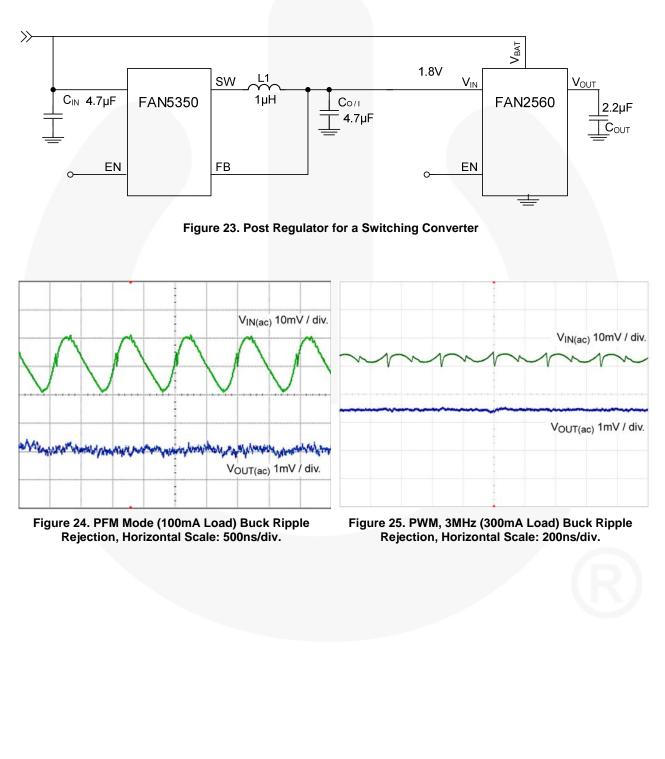
#### Table 1. Recommended Capacitors

Capacitance	Size	Vendor	Part number
1μF	0603	MURATA	GRM188R71C105KA120
2.2µF	0603	MURATA	GRM188R61A225KF340
2.2µF	0402	MURATA	GRM155R60J225ME15

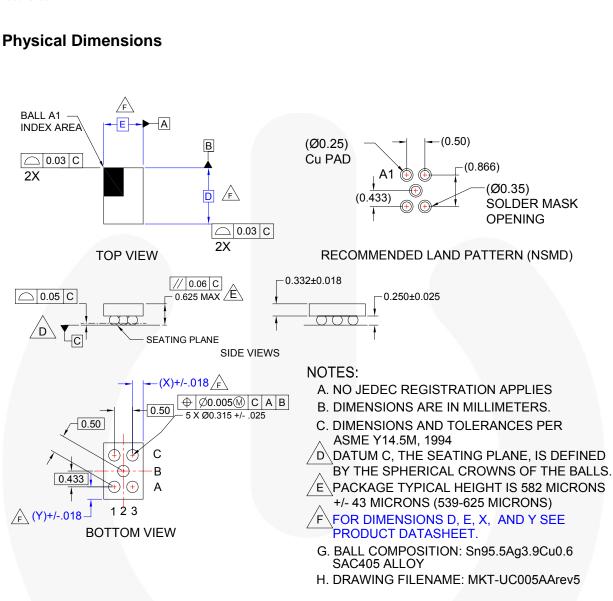
#### Application Example: Post Regulator for a Switching Converter

The FAN2560 is an ideal choice for battery-powered equipment. The low quiescent bias current can be supplied directly from the battery, while the input voltage can come from a high-efficiency buck regulator, like FAN5350. This combination provides both best

efficiency and low noise output. As can be seen in the scope pictures below the schematic, the already-low output voltage ripple, inherent to a switching regulator, is significantly attenuated by the FAN2560 at any frequency within the switching operating range.



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#### Figure 26. Wafer-Level Chip-Scale Packaging (WLCSP)

## **Product Specific Dimensions**

Product	D	E	Х	Y
FAN2560UC13X	0.960 +/- 0.030	1.330 +/- 0.030	0.230	0.232
FAN2560UC15X	0.960 +/- 0.030	1.330 +/- 0.030	0.230	0.232

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FAN2560

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350mA Low-V<sub>IN</sub> LDO with Fast Transient Response

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